

Product data sheet

## **1** General description

The BGU8053 is, also known as the BTS1001H, a low noise high linearity amplifier for wireless infrastructure applications, equipped with fast shutdown to support TDD systems. The LNA has a high input and output return loss and is designed to operate between 2 GHz and 6 GHz. It is housed in a 2 mm × 2 mm × 0.75 mm 8-terminal plastic thin small outline package. The LNA is ESD protected on all terminals.

## 2 Features and benefits

- Low noise performance: NF = 0.56 dB
- High linearity performance: IP3<sub>O</sub> = 36 dBm
- High input return loss > 12 dB
- High output return loss > 20 dB
- Unconditionally stable up to 20 GHz
- Programmable bias current (via resistor)
- Small 8-terminal leadless package 2 mm × 2 mm × 0.75 mm
- · ESD protection on all terminals
- · Moisture sensitivity level 1
- · Fast shut down to support TDD systems
- 3 V to 5 V single supply

## 3 Applications

- Wireless infrastructure
- · Low noise and high linearity applications
- LTE, W-CDMA, CDMA, GSM
- General-purpose wireless applications
- TDD or FDD systems
- Suitable for small cells



# 4 Quick reference data

#### Table 1. Quick reference data

f = 2500 MHz;  $V_{CC} = 5 \text{ V}$ ;  $T_{amb} = 25 \text{ °C}$ ; input and output 50  $\Omega$ ;  $R \sim bias = 5.1 \text{ k}\Omega$ ; unless otherwise specified. All RF parameters are measured in an application board as shown in Figure 16 with components listed in Table 9 optimized for f = 2500 MHz.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CC</sub>	supply current	on state	36	48	60	mA
		off state	-	2.8	-	mA
G <sub>ass</sub>	associated gain	on state	17	18.5	20	dB
		off state	-	-23.5	-	dB
NF	noise figure	[1]	-	0.56	0.75	dB
P <sub>L(1dB)</sub>	output power at 1 dB gain compression		-	18	-	dBm
IP3 <sub>0</sub>	output third-order intercept point	2-tone; tone spacing = 1 MHz; $P_i$ = -15 dBm per tone	32	36	-	dBm

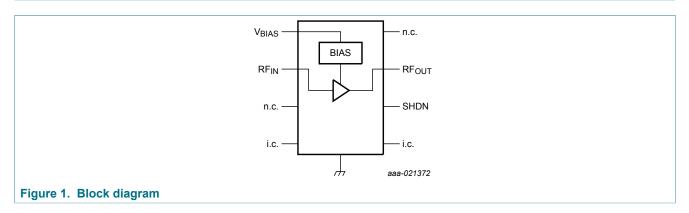
[1] Connector and Printed-Circuit Board (PCB) losses have been de-embedded.

# 5 Ordering information

Table 2. Ordering information
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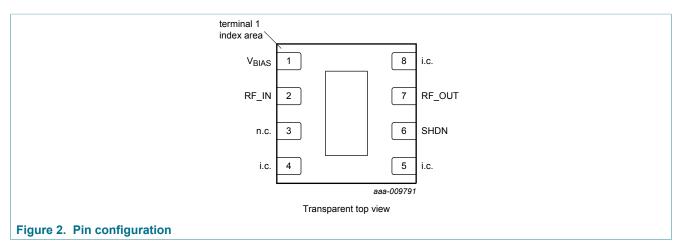
Type number	Package								
	Name	Description	Version						
BGU8053	HWSON8	plastic thermal enhanced very very thin small outline package; no leads; 8 terminals; body 2 × 2 × 0.75 mm	SOT1327-1						

# 6 Block diagram



# 7 Pinning information

# 7.1 Pinning



## 7.2 Pin description

Table 3. Pin	Table 3. Pin description							
Symbol	Pin	Description						
V <sub>BIAS</sub>	1	bias voltage						
RF_IN	2	RF input						
n.c.	3	not connected						
i.c.	4, 5, 8	internally connected. Can be grounded or left open in the application						
SHDN	6	shutdown						
RF_OUT	7	RF output						
GND	exposed die pad	ground						

#### **Limiting values** 8

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-	6	V
V <sub>ctrl(sd)</sub>	shutdown control voltage			-	3	V
I <sub>CC</sub>	supply current			-	85	mA
P <sub>i(RF)CW</sub>	continuous waveform RF input power			-	20	dBm
T <sub>stg</sub>	storage temperature			-40	+150	°C
Tj	junction temperature			-	150	°C
Р	power dissipation	T <sub>case</sub> ≤ 125 °C	[1]	-	510	mW
V <sub>ESD</sub>	electrostatic discharge voltage	Human Body Model (HBM) According to ANSI/ESDA/JEDEC standard JS-001-2010		-	1.5	kV
		Charged Device Model (CDM); According to JEDEC standard 22-C101B		-	2	kV

Case is ground solder pad. [1]

#### **Recommended operating conditions** 9

#### Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V <sub>CC</sub>	supply voltage		3.3	5	5.25	V
Z <sub>0</sub>	characteristic impedance		-	50	-	Ω
T <sub>case</sub>	case temperature		-40	-	+85	°C

## **10** Thermal characteristics

#### Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-case)</sub>	thermal resistance from junction to case	[1] [2]	50	K/W

[1]

Case is ground solder pad. Thermal resistance measured using infrared measurement technique, device mounted on application board and placed in still air. [2]

# **11 Characteristics**

#### Table 7. Characteristics

f = 2500 MHz; V<sub>CC</sub> = 5 V; T<sub>amb</sub> = 25 °C; input and output 50 Ω;  $R_{bias}$  = 5.1 kΩ; unless otherwise specified. All RF parameters are measured in an application board as shown in Figure 16 with components listed in Table 9 optimized for f = 2500 MHz

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CC</sub>	supply current	on state	36	48	60	mA	
		off state		-	2.8	-	mA
G <sub>ass</sub>	associated gain	on state		17	18.5	20	dB
		off state		-	-23.5	-	dB
NF	noise figure		[1]	-	0.56	0.75	dB
P <sub>L(1dB)</sub>	output power at 1 dB gain compression			-	18	-	dBm
IP3 <sub>0</sub>	output third-order intercept point	2-tone; tone spacing = 1 MHz;P <sub>i</sub> = -15 dBm per tone		32	36	-	dBm
		2-tone; tone spacing = 1 MHz; $P_i$ = -15 dBm per tone	[2]	30	34	-	dBm
RL <sub>in</sub>	input return loss	on state		-	12.2	-	dB
		off state		-	6.3	-	dB
RL <sub>out</sub>	output return loss			-	28.0	-	dB
ISL	isolation			-	22.0	-	dB
t <sub>s(pon)</sub>	power-on settling time	P <sub>i</sub> = -20 dBm; SHDN (pin 6) from HIGH to LOW	[2]	-	1.4	-	μs
t <sub>s(poff)</sub>	power-off settling time	P <sub>i</sub> = -20 dBm; SHDN (pin 6) from LOW to HIGH	[2]	-	0.4	-	μs
К	Rollett stability factor	both on state and off state up to f = 20 GHz		1	-	-	
R <sub>pd(SHDN)</sub>	pull-down resistance on pin SHDN			-	30	-	kΩ

[1] Connector and Printed-Circuit Board (PCB) losses have been de-embedded.

[2] For TDD systems where fast switching is required, the value of C1 and C2 should be changed to 100 pF.

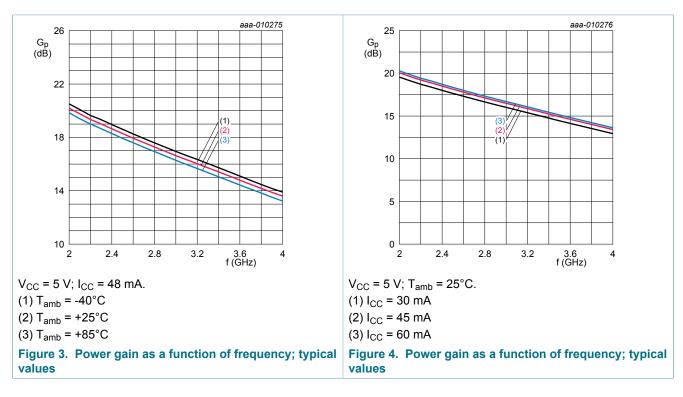
#### Table 8. Shutdown control

 $V_{CC}$  = 5 V;  $T_{amb}$  = 25 °C; input and output 50  $\Omega$ ;  $R_{bias}$  = 5.1 k $\Omega$ ; unless otherwise specified. All RF parameters are measured in an application board as shown in Figure 16 with components listed in Table 9 optimized for f = 2500 MHz

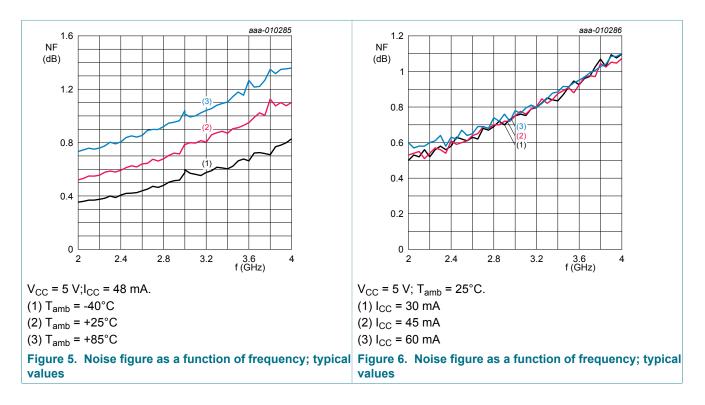
State	V <sub>ctrl(sd)</sub> <sup>[1]</sup>	Unit
on state	≤ 0.6	V
off state	≥ 1.2	V

[1] Voltage on pin 6 (SHDN).

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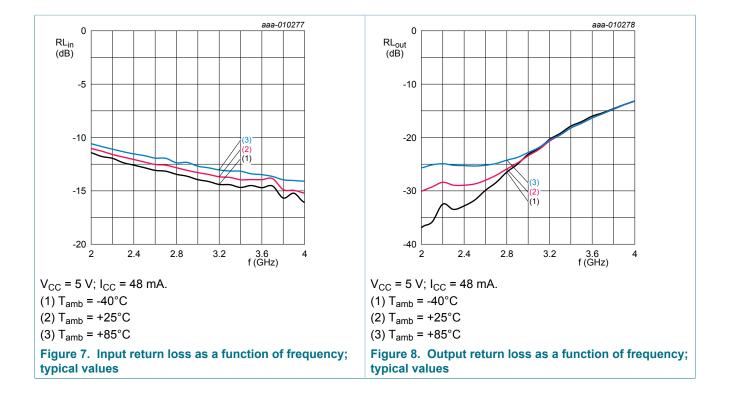


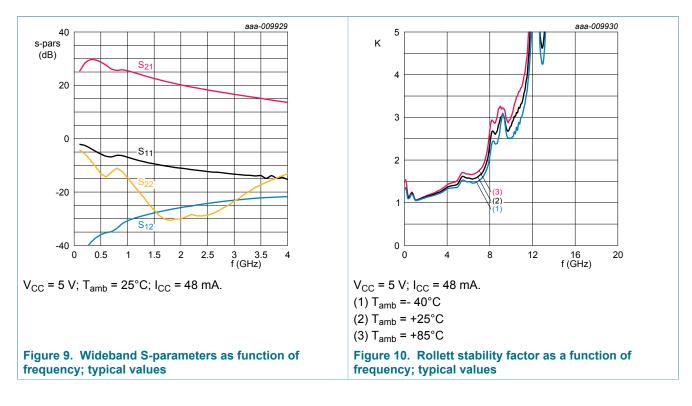
#### **11.1 Graphics**



# **BGU8053**

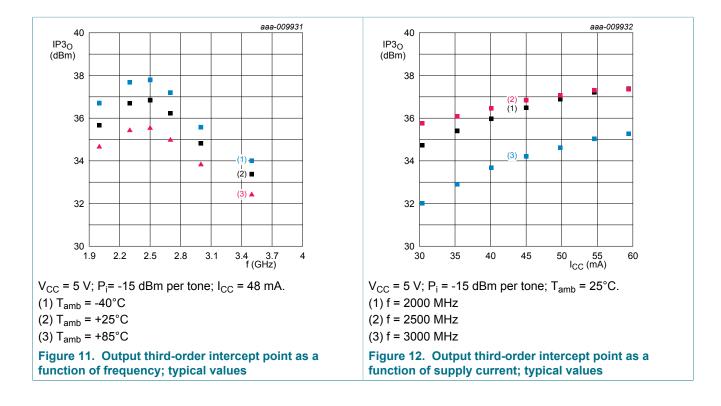
#### Low noise high linearity amplifier

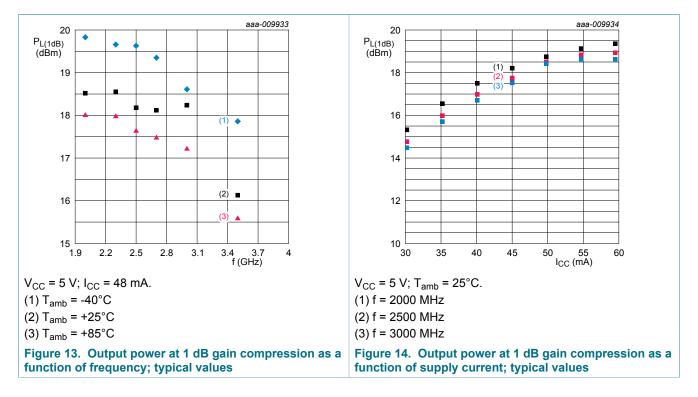




# **BGU8053**

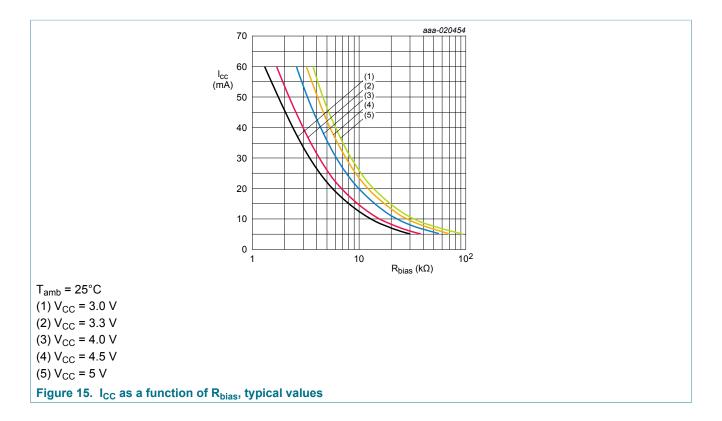
#### Low noise high linearity amplifier



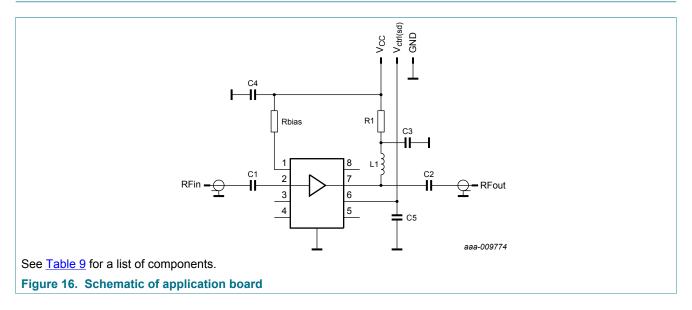


# **BGU8053**

#### Low noise high linearity amplifier



# **12** Application information



## Table 9. List of components

See figure 16 for schematics.

Component	Description	Value	Remarks
C1, C2	capacitor	100 nF	
		100 pF	recommended for TDD systems
C3, C5	capacitor	10 pF	
C4	capacitor	10 nF	
L1	inductor	15 nH	
R1	resistor	10 Ω	
R <sub>bias</sub>	resistor	5.1 kΩ	V <sub>CC</sub> = 5 V
		2.3 kΩ	V <sub>CC</sub> = 3.3 V

# **BGU8053**

#### Low noise high linearity amplifier

#### Table 10. Typical performance BGU8053 application board V<sub>CC</sub> = 5 V

All RF parameters are measured at the application board as shown in figure 16. With the components as listed in Table 9 while optimized for: f = 2500 MHz,  $V_{CC} = 5 \text{ V}$ ,  $I_{CC} = 48 \text{ mA}$  and  $T_{amb} = 25 \text{ °C}$ .

Symbol	Parameter		f (MHz)							
			2000	2300	2500	2700	3000	3400	3500	3800
G	gain		20.2	19.0	18.3	17.6	16.6	15.4	15.1	14.2
RL <sub>in</sub>	input return loss		11.0	11.8	12.3	12.6	13.3	14.0	13.8	14.9
RL <sub>out</sub>	output return loss		30.1	28.9	28.7	27.1	23.4	18.2	17.3	14.7
P <sub>L(1dB)</sub>	output power at 1 dB gain compression		18.5	18.6	18.2	18.1	18.2	16.9	16.2	14.9
IP3 <sub>0</sub>	output third-order	[1]	35.5	35.4	35.4	35.2	34.3	33.4	33.3	32.5
intercept point	[1] [2]	34.8	36.3	36.3	36.4	35.6	32.5	33.1	31.9	
NF	noise figure	[3]	0.52	0.59	0.63	0.68	0.67	0.76	0.78	0.87

[1]

2-Tone; tone spacing = 1 MHz,  $P_{\rm o}$  = 5 dBm per tone. For applications where fast switching is required, the value of C1 and C2 should be changed to 100 pF. Connector and board losses not de-embedded. [2] [3]

### Table 11. Typical performance BGU8053 application board $V_{CC}$ = 3.3 V

All RF parameters measured at application board shown in figure 16. With the components as listed in Table 9 while optimized for 2500 MHz,  $V_{CC}$  = 3.3 V,  $I_{CC}$  = 48 mA,  $T_{amb}$  =25°C

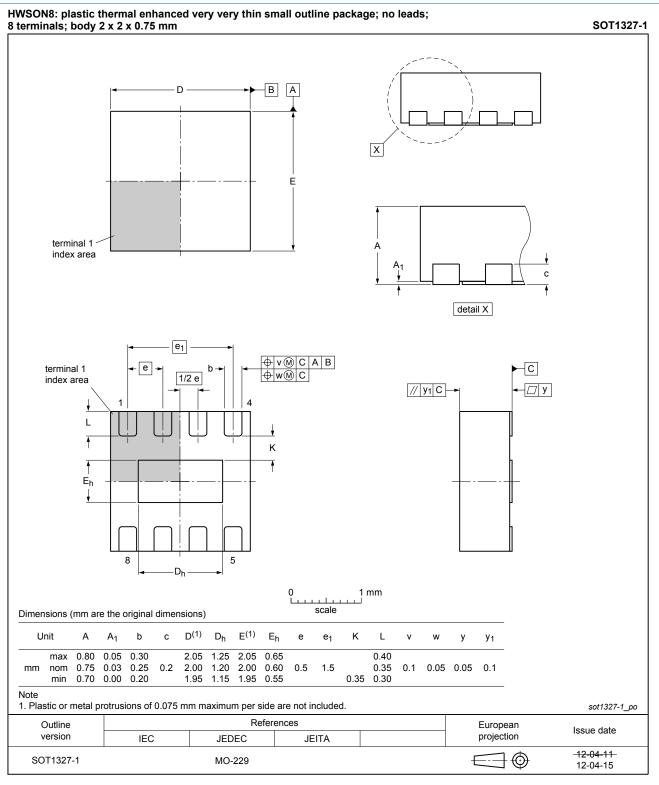
Symbol	Parameter		f (MHz)							
			2000	2300	2500	2700	3000	3400	3500	3800
G	gain		20.2	18.9	18.1	17.4	16.4	15.3	15.0	14.1
RL <sub>in</sub>	input return loss		11.3	12.1	12.4	14.1	13.6	13.7	15.0	15.3
RL <sub>out</sub>	output return loss		32.9	29.5	27.8	27.5	23.4	18.6	17.7	15.4
P <sub>L(1dB)</sub>	output power at 1 dB gain compression		10.0	11.4	12.4	12.2	12.4	14.0	12.8	12.7
IP3 <sub>0</sub>	output third-order	[1]	30.5	30.3	28.8	29.3	27.8	29.5	27.9	26.1
	intercept point	[1] [2]	31.0	30.7	28.8	29.3	27.4	29.4	27.6	26.0
NF	noise figure	[3]	0.55	0.58	0.60	0.63	0.69	0.78	0.80	0.89

2-Tone; tone spacing = 1 MHz,  $P_0 = 5$  dBm per tone. For TDD systems C1 and C2 have to be 100 pF. [1]

[2] [3]

Connector and board losses not de-embedded.

# 13 Package outline



#### Figure 17. Package outline SOT1327-1 (HWSON8)

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BGU8053

# **14 Abbreviations**

Table 12. Abbreviations				
Acronym	Description			
CDMA	Code Division Multiple Access			
ESD	ElectroStatic Discharge			
FDD	Frequency-Division Duplexing			
GSM	Global System for Mobile Communication			
LNA	Low Noise Amplifier			
LTE	Long-Term Evolution			
RF	Radio Frequency			
TDD	Time-Division Duplexing			
W-CDMA	Wideband Code Division Multiple Access			

# **15 Revision history**

Table 13. Revision history								
Document ID	Release date	Data sheet status	Change notice	Supersedes				
BGU8053 v.7	201707017	Product data sheet	-	BGU8053 v.6				
Modifications:	Section 11.1 has be	<u>Section 11.1</u> has been changed						
BGU8053 v.6	20170608	Product data sheet	-	BGU8053 v.5				
Modifications:	• Table 4: the maxim	<ul> <li><u>Table 4</u>: the maximum value of V<sub>ESD</sub> has been changed into 1.5 kV</li> </ul>						
BGU8053 v.5	20170502	Product data sheet	-	BGU8053 v.4				
Modifications:	<ul> <li><u>Table 5 "Recommended operating conditions"</u>: the minimum value of V<sub>CC</sub> has been changed into 3.3 V</li> </ul>							
BGU8053 v.4	20170120	Product data sheet	-	BGU8053 v.3				
Modifications:	<u>Section 1 "General description"</u> : added BTS1001H according to our new naming convention							
BGU8053 v.3	20160418	Product data sheet	-	BGU8053 v.2				
Modifications:	<ul> <li>3 V to 5 V single supply added to <u>Section 2 "Features and benefits"</u></li> <li>Added <u>Figure 1 "Block diagram" on page 2</u></li> <li>An additional curve added <u>Figure "Output power at 1 dB gain compression as a function of supply current: typical values" on page 8</u></li> <li>Added remark to R<sub>bias</sub> in <u>Table 9 "List of components"</u></li> <li>Added <u>Table 11 "Typical performance BGU8053 application board VCC = 3.3 V" on page 11</u></li> </ul>							
BGU8053 v.2	20131230	Product data sheet	-	BGU8053 v.1				
Modifications:	- Table 4 on page 3: The maximum value for $V_{ctrl(sd)}$ has been corrected to 3 V.							
BGU8053 v.1	20131127	Product data sheet	-	-				

# **16 Legal information**

## 16.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

Please consult the most recently issued document before initiating or completing a design. [1]

The term 'short data sheet' is explained in section "Definitions".

[2] [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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BGU8053 **Product data sheet** 

# **BGU8053**

#### Low noise high linearity amplifier

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# **BGU8053**

Low noise high linearity amplifier

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